

IRFHM8363TRPBF

IRFHM8363TRPBF Information

Heisener.com	 IRFHM8363TRPBF Infineon Technologies Discrete Semiconductor Products Transistors - FETs, MOSFETs - Arrays MOSFET 2N-CH 30V 11A 8PQFN 8-PowerVDFN For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IRFHM8363TRPBF Specifications

Manufacturer Part Number	IRFHM8363TRPBF	
Manufacturer	Infineon Technologies	
Category	Discrete Semiconductor Products	
	Transistors - FETs, MOSFETs - Arrays	
Package	8-PowerVDFN	
Series	HEXFET?	
FET Type	2 N-Channel (Dual)	
FET Feature	Logic Level Gate	
Drain to Source Voltage (Vdss)	30V	
Current - Continuous Drain (Id) @ 25°C	11A	
Rds On (Max) @ Id, Vgs	14.9 mOhm @ 10A, 10V	
Vgs(th) (Max) @ Id	2.35V @ 25µA	
Gate Charge (Qg) (Max) @ Vgs	15nC @ 10V	
Input Capacitance (Ciss) (Max) @ Vds	1165pF @ 10V	
Power - Max	2.7W	
Operating Temperature	-55°C ~ 150°C (TJ)	
Mounting Type	Surface Mount	
Package / Case	8-PowerVDFN	
Supplier Device Package	8-PQFN (3.3x3.3), Power33	
	Report errors?	

IRFHM8363TRPBF Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IRFHM8363TRPBF Payment Methods



If you have any question about IRFHM8363TRPBF, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com